

Electronic Supplementary Information

Impact of charge transport layers on photochemical stability of MAPbI₃ in thin films and perovskite solar cells

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Figure S13. Evolution of EQE spectra of ITO/PEDOT:PSS/MAPbI₃/PC₆₁BM/Mg/Ag (a), ITO/PEDOT:PSS/MAPbI₃/PC₇₁BM/Mg/Ag (b) and ITO/SnO₂/MAPbI₃/spiro-OMeTAD/Ag/Au (c) solar cells fabricated using fresh films and top electrode free stacks exposed to light soaking. 10

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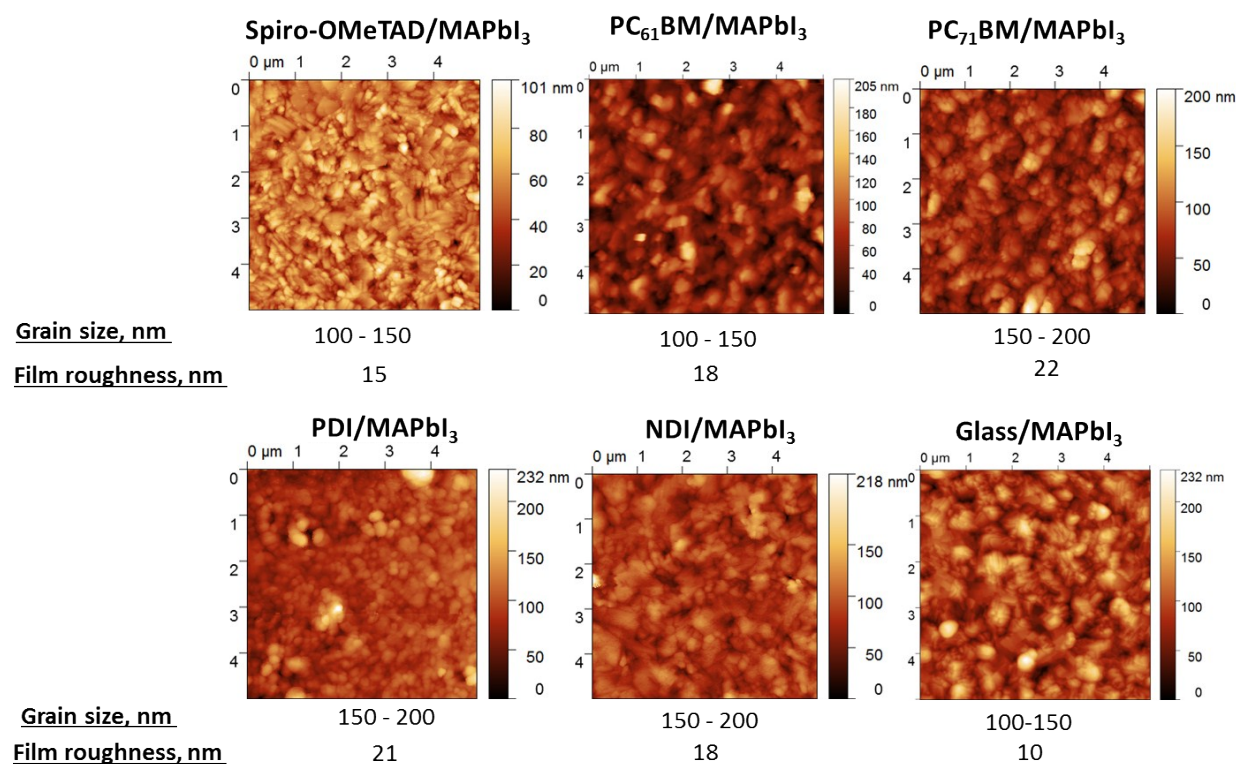


Figure S1. AFM surface topography of CTL/MAPbI₃ films before light soaking

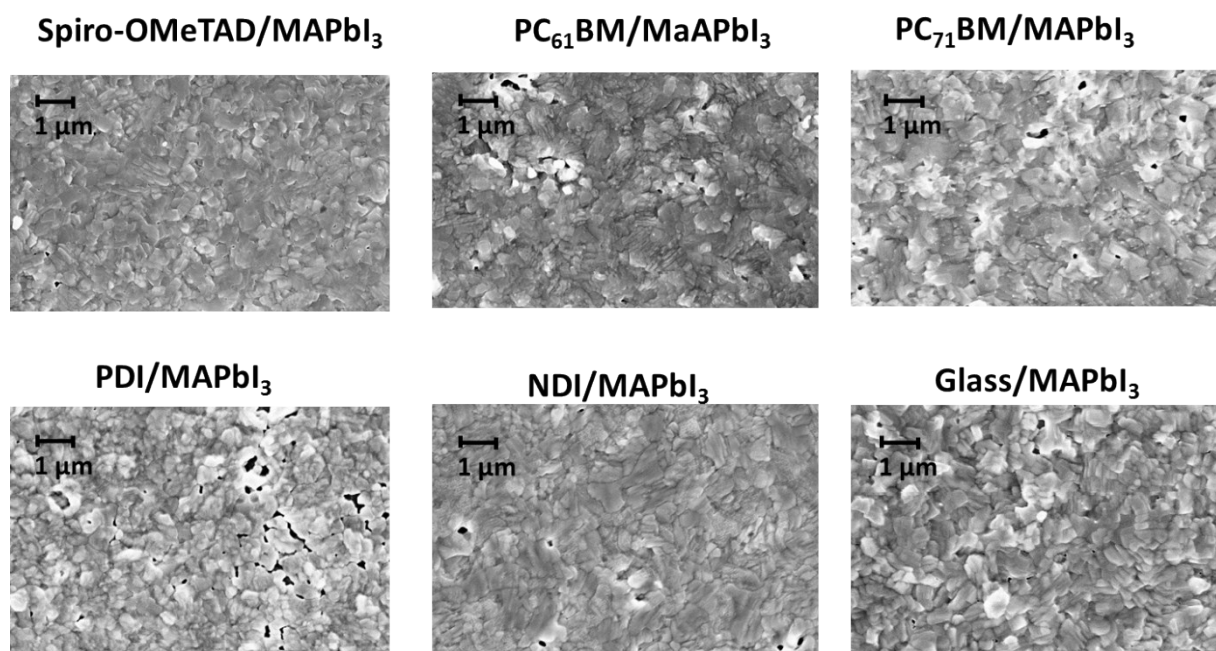


Figure S2. SEM images of CTL/MAPbI₃ films before light soaking

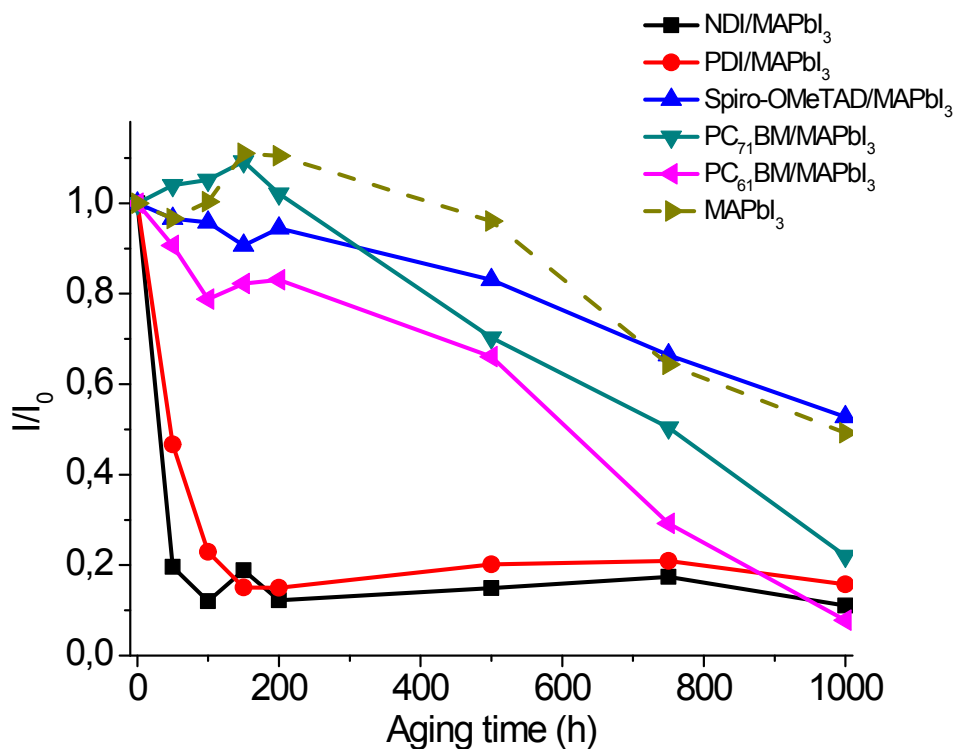


Figure S3. Evolution of the optical density of glass/CTL/MAPbI₃ stacks at 700 nm (I_0 stands for initial optical density at this wavelength).

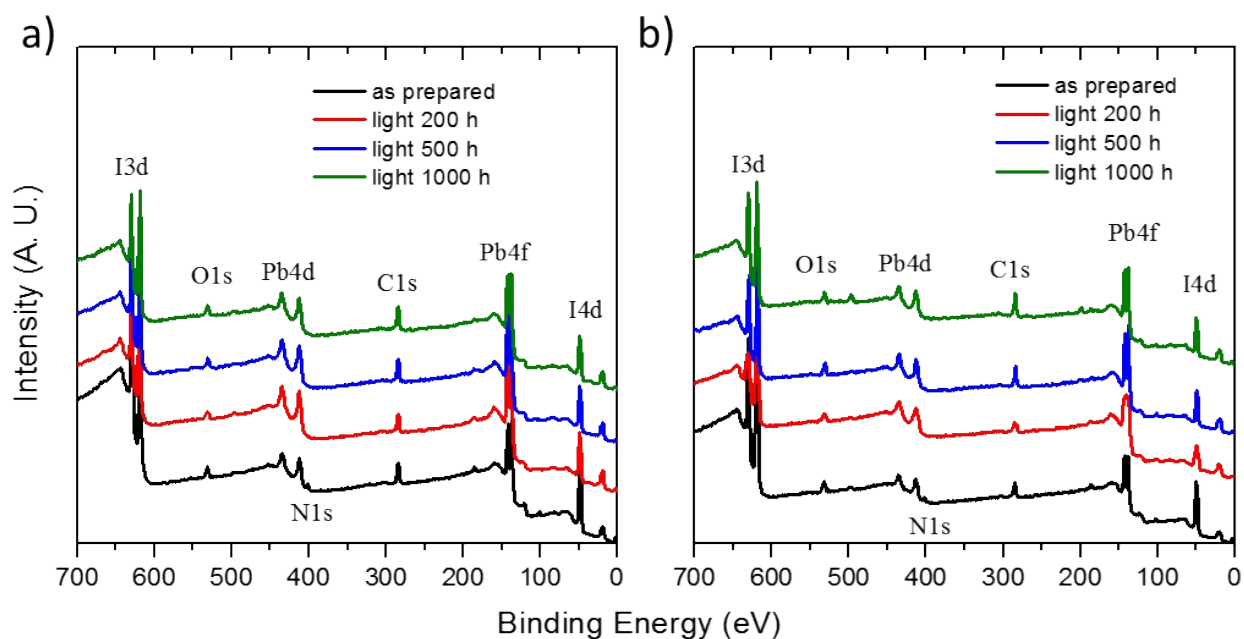


Figure S4. Evolution of the XPS survey spectra of glass/NDI/MAPbI₃ (a) and glass/PDI/MAPbI₃ (b) stacks under light soaking conditions.

Table S1. Surface composition (in at.%) of glass/NDI/MAPbI₃ and glass/PDI/MAPbI₃ samples estimated from XPS spectra.

Configuration	Aging time (h)	Surface composition (at. %)			Element ratio	
		N	Pb	I	I:Pb	N:Pb
NDI/MAPbI ₃	0	6.1	9.7	23.8	2.45	0.62
	500	1.7	7.4	16.3	2.20	0.22
	1000	0.9	11.1	14.4	1.29	0.08
PDI/MAPbI ₃	0	7.5	8.6	21.7	2.52	0.87
	500	0	10.3	13.1	1.27	0
	1000	0	8.6	12.5	1.45	0

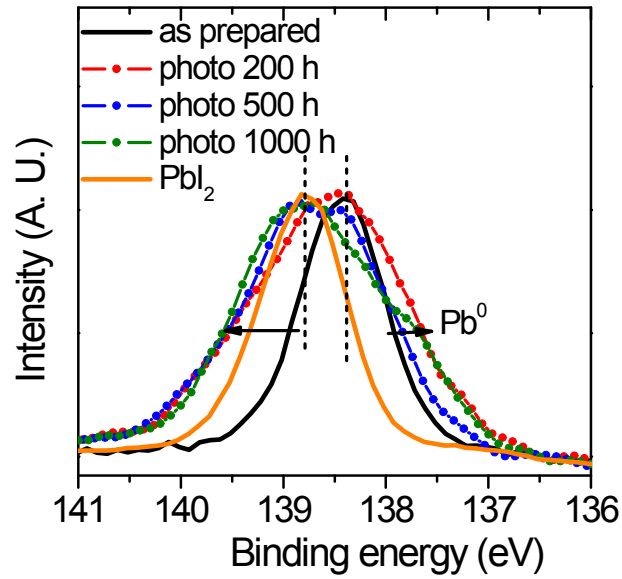


Figure S5. Evolution of the XPS Pb 4f_{7/2} band for glass/PDI/MAPbI₃ stacks under light soaking conditions.

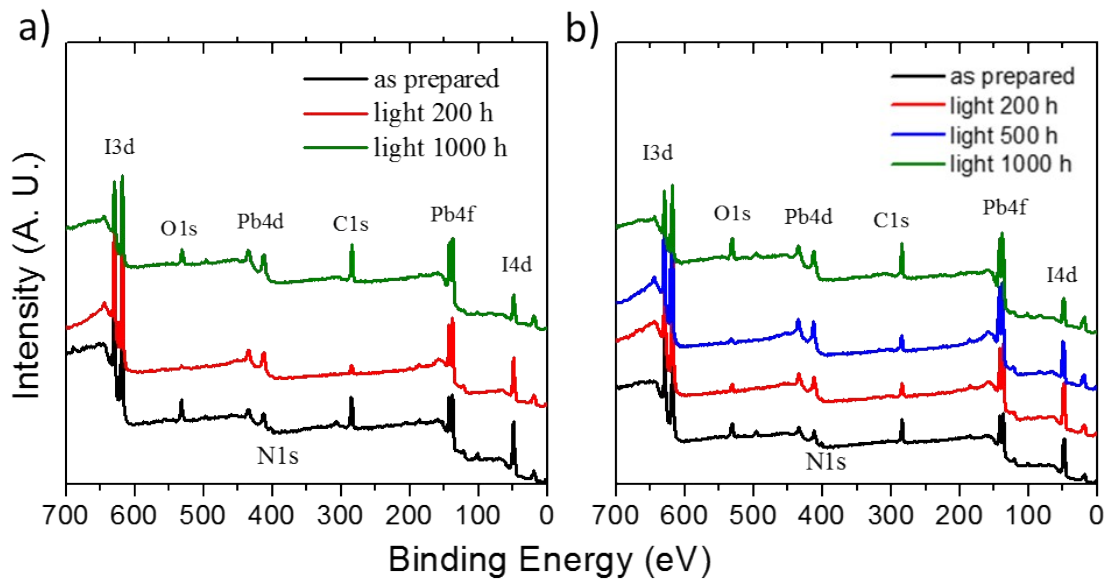


Figure S6. Evolution of the XPS survey spectra of glass/PC₆₁BM/MAPbI₃ (a) and glass/PC₇₁BM/MAPbI₃ (b) samples under light soaking conditions.

Table S2. Surface composition (in at.%) of PC₆₁BM/MAPbI₃ and PC₇₁BM/MAPbI₃ samples estimated from XPS spectra

Configuration	Aging time (h)	Surface composition (at. %)			Element Ratio	
		N	Pb	I	I:Pb	N:Pb
PC ₆₁ BM/MAPbI ₃	0	4.1	4.3	11.9	2.76	0.95
	200	3.8	15.6	32.2	2.06	0.24
	500	0	0.1	0.2	1.0	0
	1000	0	6.8	6.7	0.98	0
PC ₇₁ BM/MAPbI ₃	0	3.8	5.7	12.7	2.22	0.66
	200	5.7	11.8	24	2.03	0.48
	500	0	13.5	19.1	1.41	0
	1000	0	7.3	6.4	0.87	0

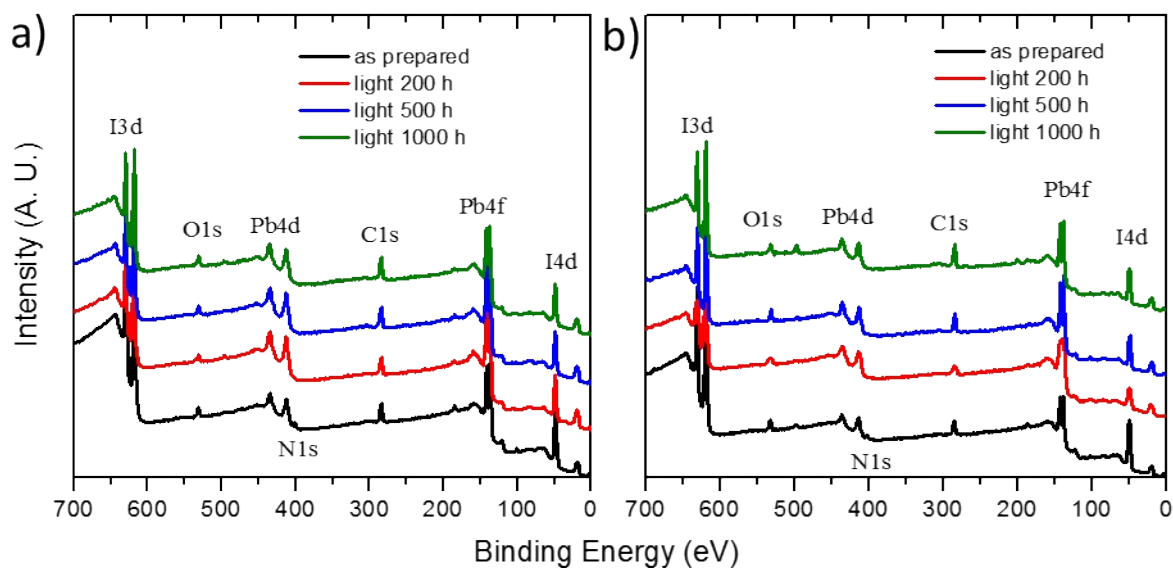


Figure S7. XPS survey spectra of spiro-OMeTAD/MAPbI₃ (a) and pristine MAPbI₃ (b) samples before and after light illumination.

Table S3. Surface composition (in at.%) of spiro-OMeTAD/MAPbI₃ (a) and pristine MAPbI₃ (b) samples estimated from XPS spectra.

Configuration	Aging time (h)	Surface composition (at. %)			Element ratio	
		N	Pb	I	I:Pb	N:Pb
Spiro-OMeTAD/MAPbI ₃	0	7.7	9.6	25.1	2.61	0.80
	200	7.8	10.8	24.4	2.25	0.72
	500	0	15.2	24.7	1.62	0
	1000	0	13.2	19.1	1.44	0
MAPbI ₃	0	6.8	9.5	25.3	2.66	0.71
	200	6.2	11	26.5	2.40	0.56
	500	0	14.8	21.1	1.42	0
	1000	0	15.5	19.9	1.28	0

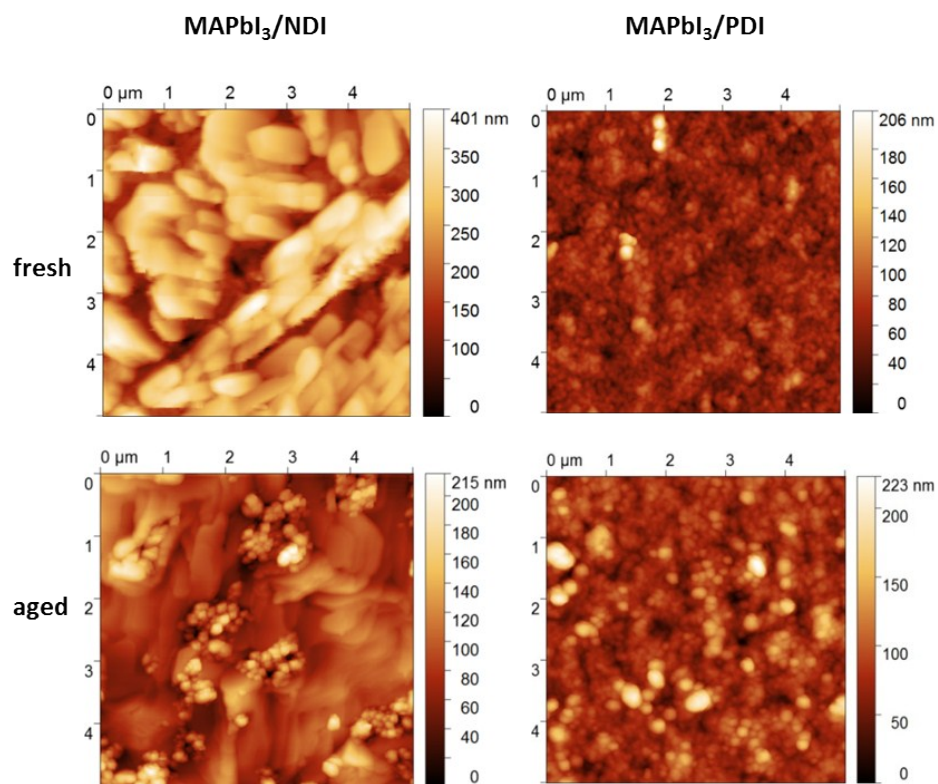


Figure S8. Surface topography of glass/MAPbI₃/NDI and glass/MAPbI₃/PDI films before and after 1000 h exposure to the light soaking.

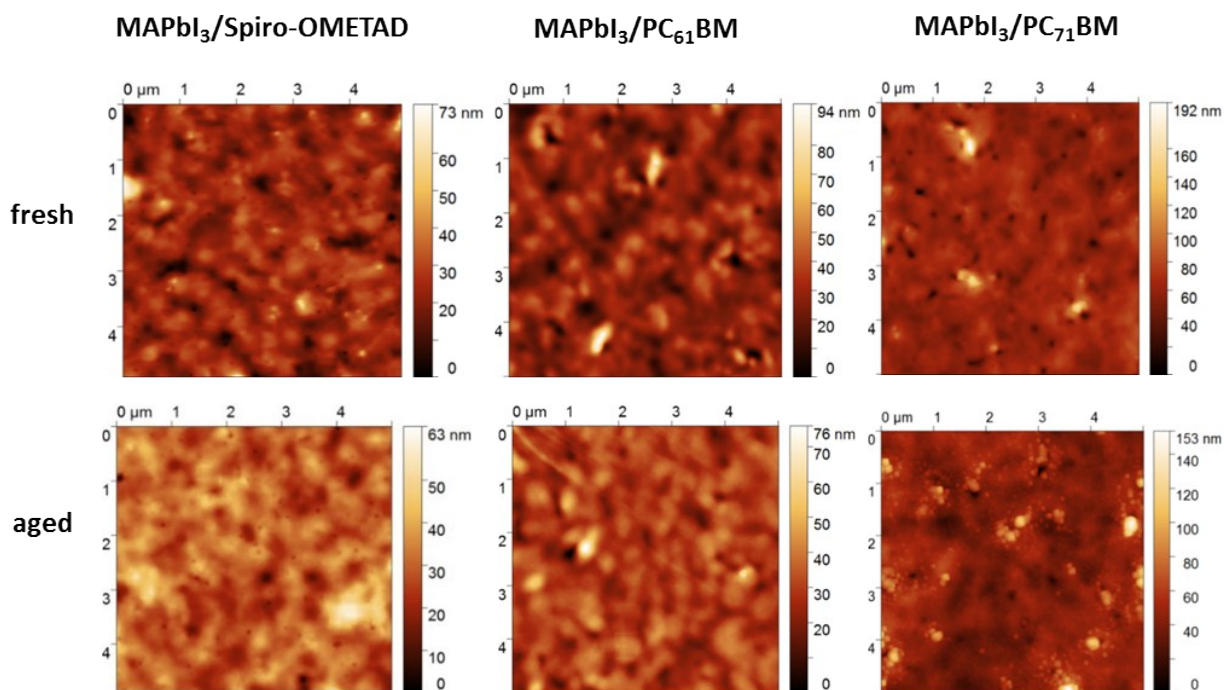


Figure S9. Surface topography of glass/MAPbI₃/Spiro-OMeTAD, glass/MAPbI₃/PC₆₁BM and glass/MAPbI₃/PC₇₁BM films before and after 1000 h exposure to the light soaking.

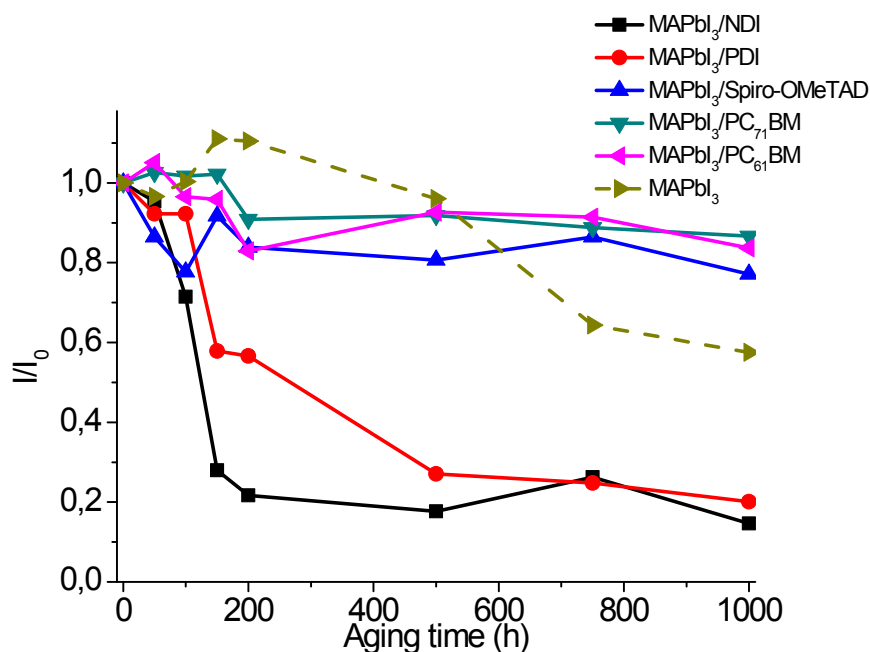


Figure S10. Evolution of the optical density of glass/MAPbI₃/CTL stacks at 700 nm (I_0 stands for initial optical density at this wavelength).

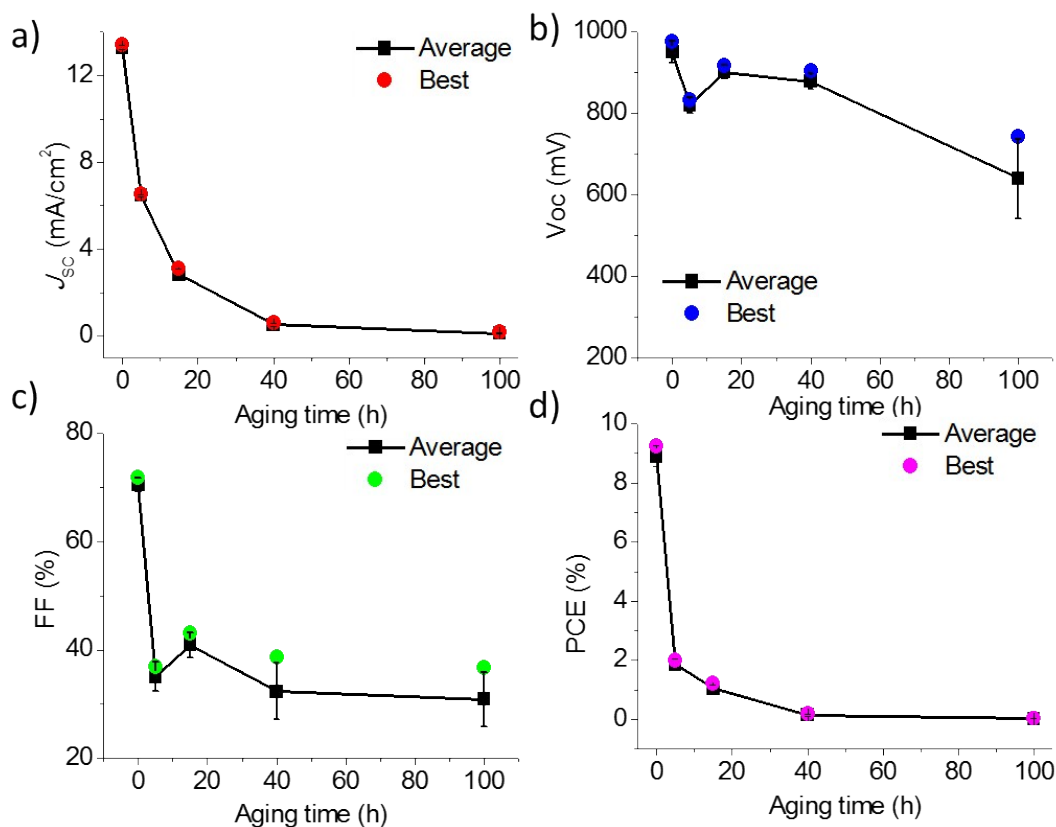


Figure S11. Evolution of the characteristics of ITO/PEDOT:PSS/MAPbI₃/PC₆₁BM/Mg/Ag solar cells under light soaking conditions applied to ITO/PEDOT:PSS/MAPbI₃/PC₆₁BM stacks: short circuit current density J_{SC} (a), open circuit voltage V_{OC} (b), fill factor FF (c) and power conversion efficiency PCE (d).

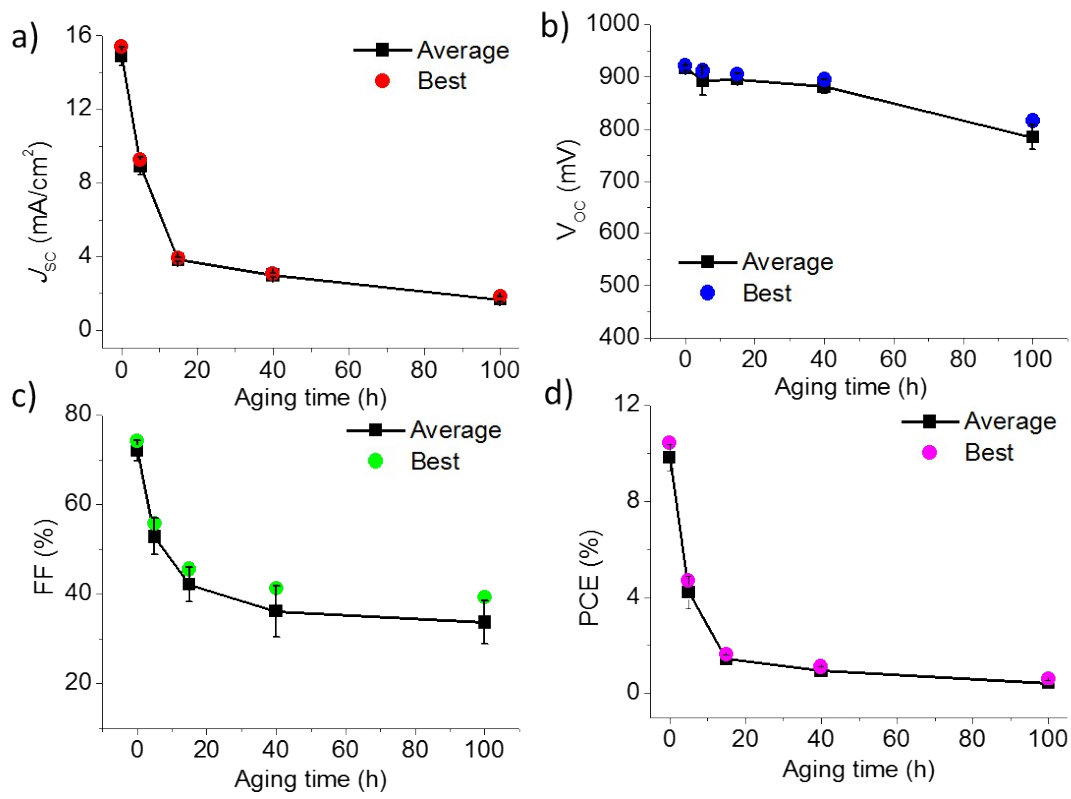


Figure S12. Evolution of the characteristics of ITO/PEDOT:PSS/MAPbI₃/PC₇₁BM/Mg/Ag solar cells under light soaking conditions applied to ITO/PEDOT:PSS/MAPbI₃/PC₇₁BM stacks: short circuit current density J_{sc} (a), open circuit voltage V_{oc} (b), fill factor FF (c) and power conversion efficiency PCE (d).

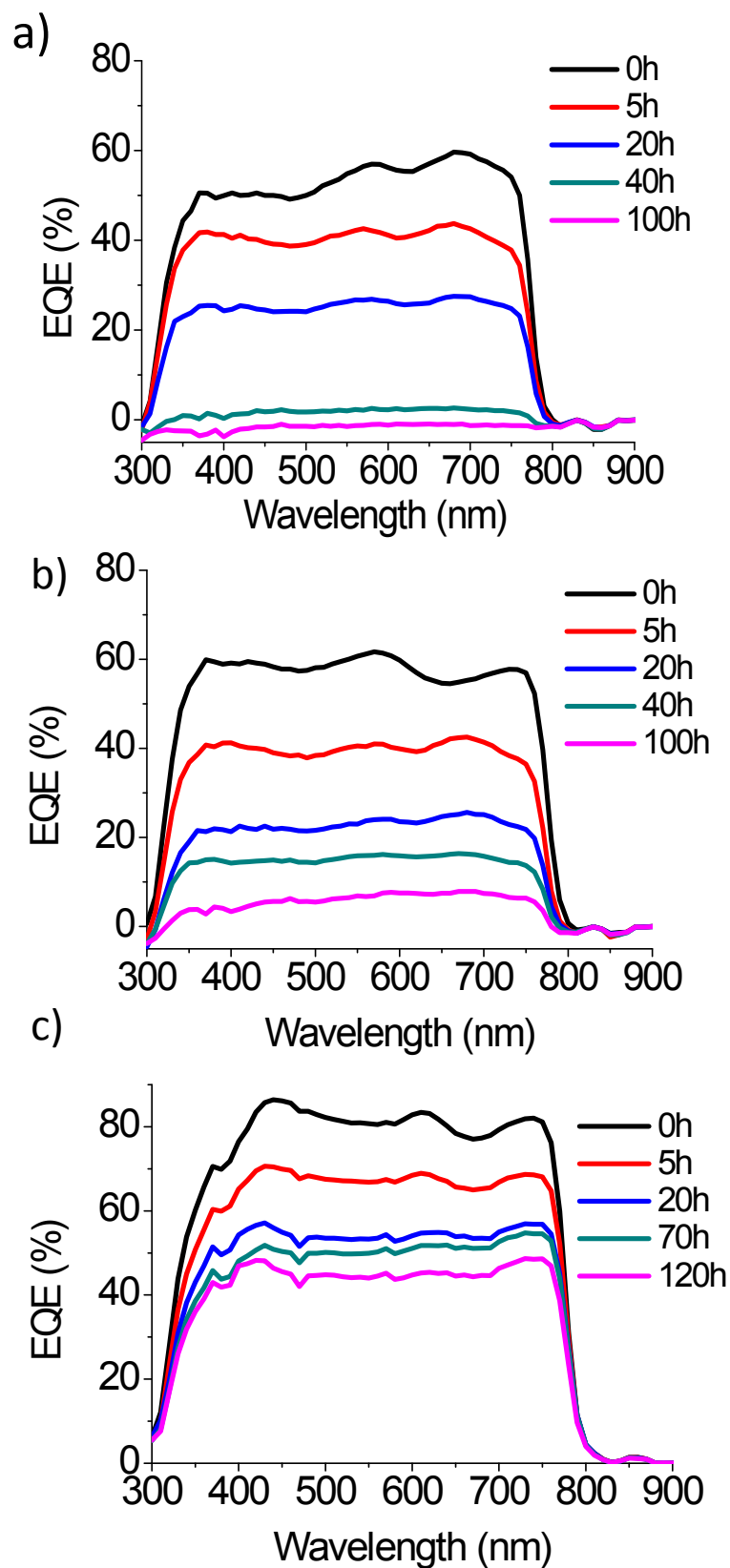


Figure S13. Evolution of EQE spectra of ITO/PEDOT:PSS/MAPbI₃/PC₆₁BM/Mg/Ag (a), ITO/PEDOT:PSS/MAPbI₃/PC₇₁BM/Mg/Ag (b) and ITO/SnO₂/MAPbI₃/spiro-OMeTAD/Ag/Au (c) solar cells fabricated using fresh and exposed to light soaking top electrode free stacks

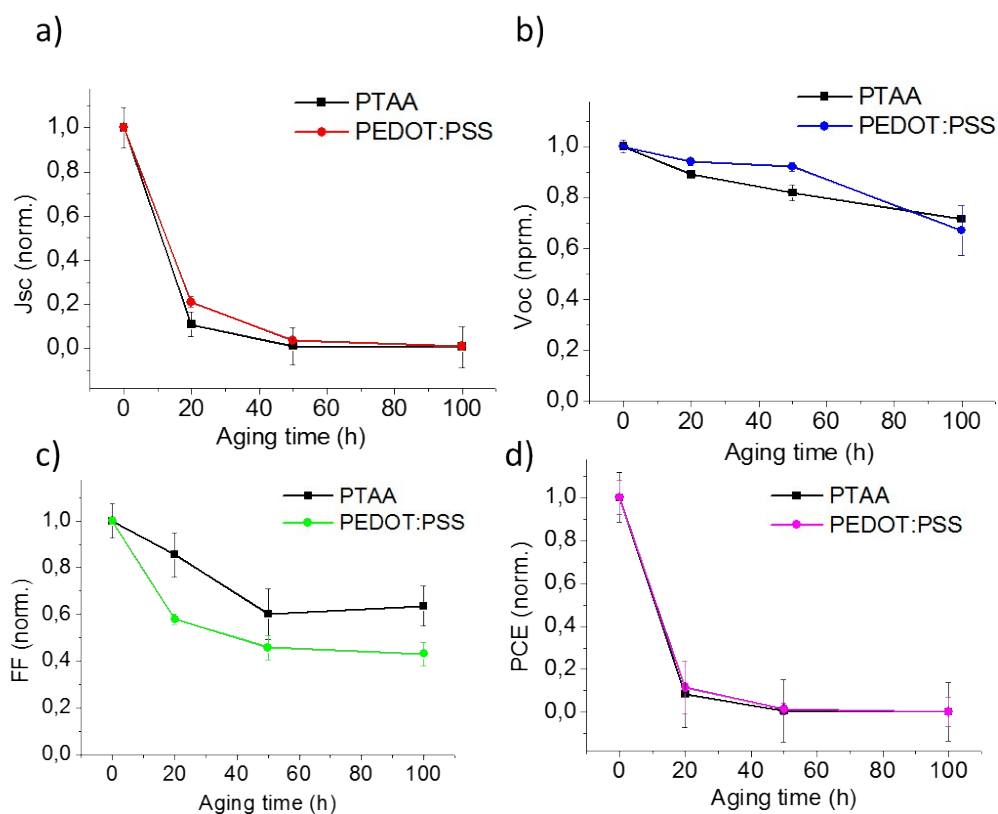


Figure S14. Comparison of the degradation behavior of ITO/PEDOT:PSS/MAPbI₃/PC₆₁BM/Mg/Ag and ITO/PTAA/MAPbI₃/PC₆₁BM/Mg/Ag solar cells under light soaking conditions applied to the electrode-free stacks: short circuit current density J_{SC} (a), open circuit voltage V_{OC} (b), fill factor FF (c) and power conversion efficiency PCE (d).

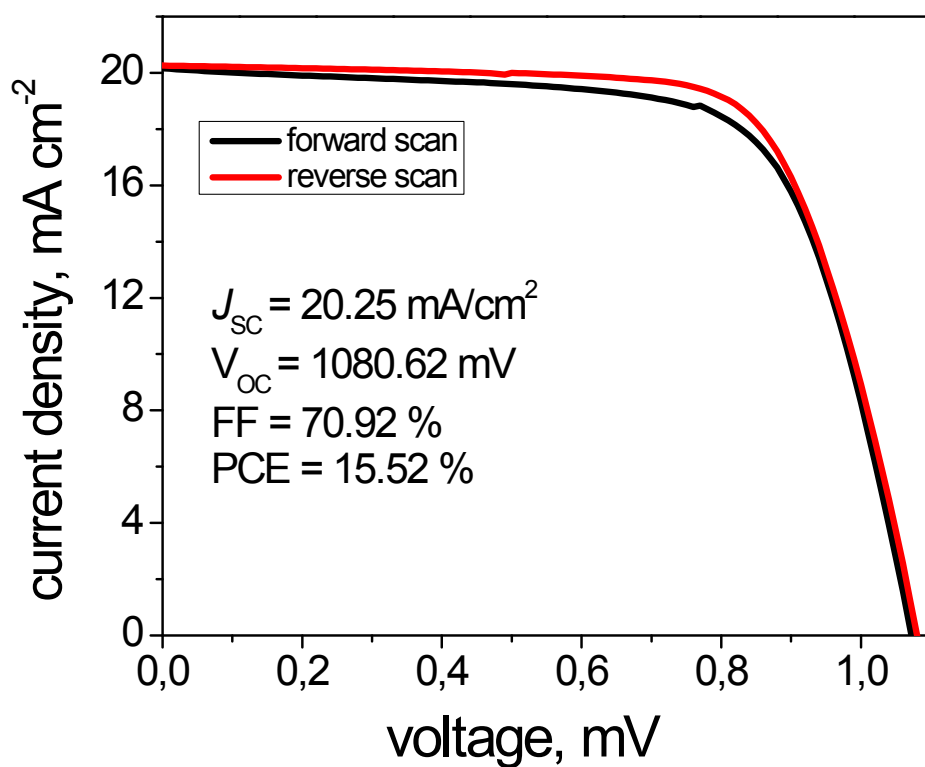


Figure S15. IV characteristics of ITO/PTAA/MAPbI₃/PC₆₁BM/Mg/Ag solar cell

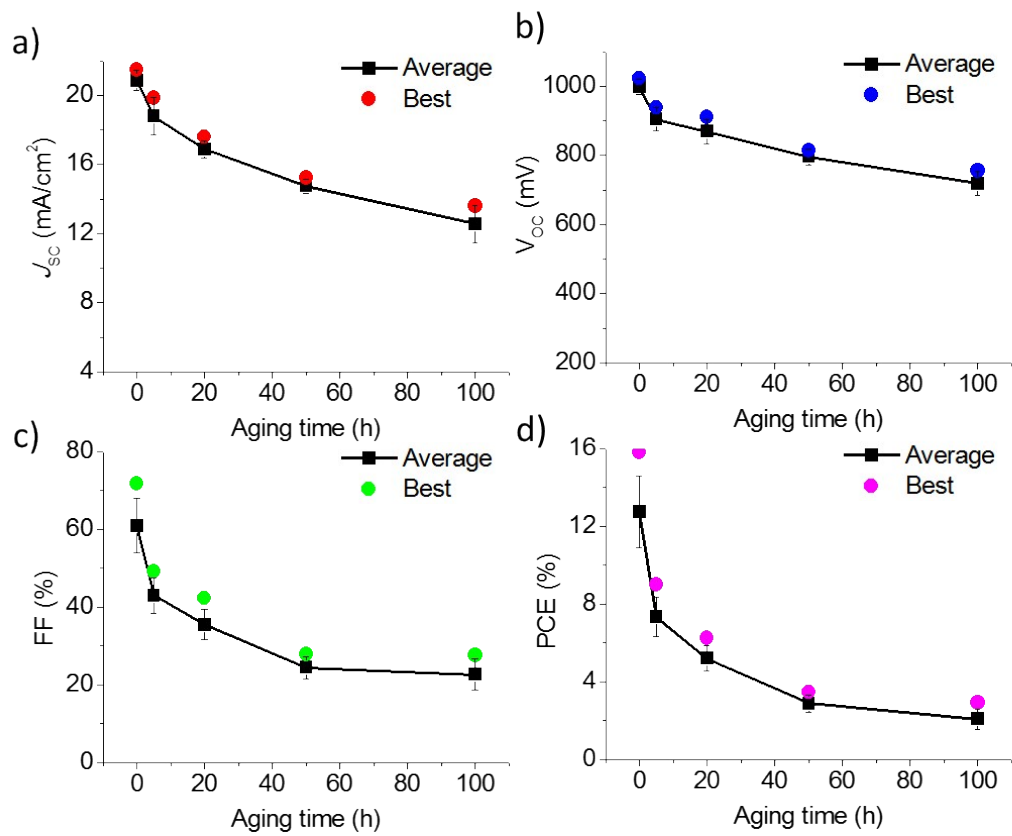


Figure S16. Evolution of the characteristics of ITO/SnO₂/MAPbI₃/Spiro-OMeTAD/Ag/Au solar cells under light soaking conditions applied to ITO/SnO₂/MAPbI₃/Spiro-OMeTAD stacks: short circuit current density J_{SC} (a), open circuit voltage V_{OC} (b), fill factor FF (c) and power conversion efficiency PCE (d).